TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC4051BP, TC4051BF, TC4051BFN, TC4051BFT TC4052BP, TC4052BF, TC4052BFN, TC4052BFT TC4053BP, TC4053BF, TC4053BFN, TC4053BFT

TC4051B

Single 8-Channel Multiplexer/Demultiplexer

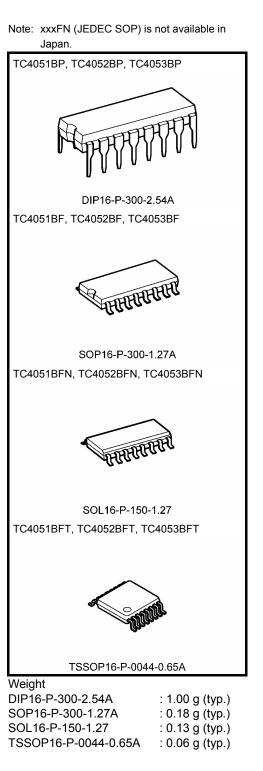
TC4052B

Differential 4-Channel Multiplexer/Demultiplexer

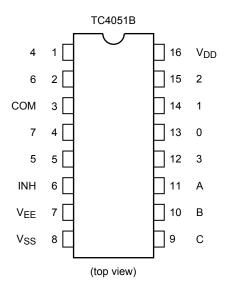
TC4053B

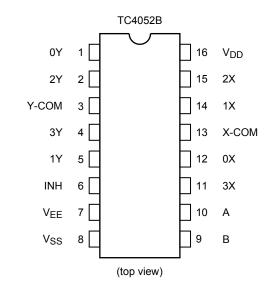
Triple 2-Channel Multiplexer/Demultiplexer

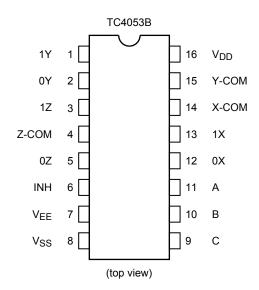
TC4051B, TC4052B and TC4053B are multiplexers with capabilities of selection and mixture of analog signal and digital signal. TC4051B has 8 channels configuration. TC4052B has 4 channel × 2 configuration and TC4053B has 2 channel × 3 configuration. The digital signal to the control terminal turns "ON" the corresponding switch of each channel, with large amplitude (V_{DD} – V_{EE}) can be switched by the control signal with small logical amplitude (V_{DD} – V_{SS}). For example, in the case of V_{DD} = 5 V V_{SS} = 0 V and V_{EE} = -5 V, signals between -5 V and +5 V can be switched from the logical circuit with single power supply of 5 volts. As the ON-resistance of each switch is low, these can be connected to the circuits with low input impedance.



Pin Assignment







Truth Table

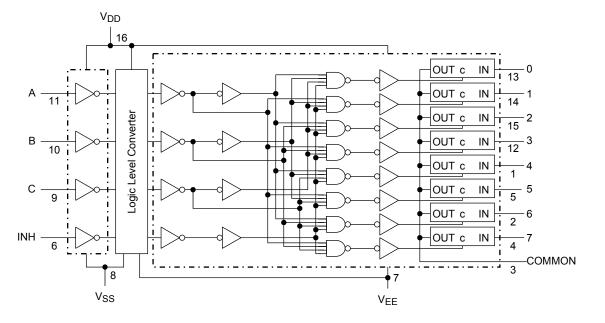
	Control	Inputs		"ON" Channel					
Inhibit	CΔ	В	А	TC4051B	TC4052B	TC4053B			
L	L	L	L	0	0X, 0Y	0X, 0Y, 0Z			
L	L	L	Н	1	1X, 1Y	1X, 0Y, 0Z			
L	L	Н	L	2	2X, 2Y	0X, 1Y, 0Z			
L	L	Н	Н	3	3X, 3Y	1X, 1Y, 0Z			
L	Н	L	L	4	—	0X, 0Y, 1Z			
L	Н	L	Н	5	—	1X, 0Y, 1Z			
L	Н	Н	L	6	—	0X, 1Y, 1Z			
L	Н	Н	Н	7	—	1X, 1Y, 1Z			
Н	Х	Х	Х	None	None	None			

X: Don't care

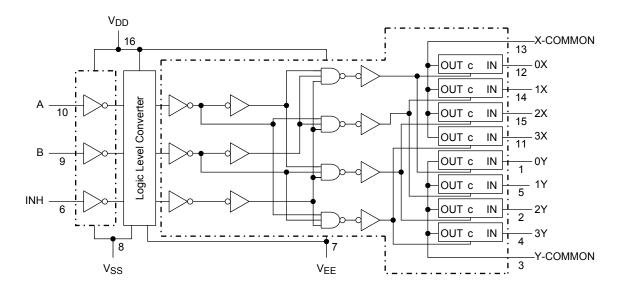
Δ: Except TC4052B

Logic Diagram

TC4051B

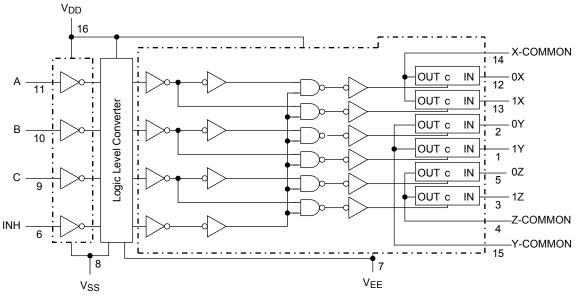


TC4052B



TC4053B

TOSHIBA



Truth Table

Control C	Impedance between IN-OUT	(Note)
Н	0.5 to 5 \times 10 2 Ω	
L	>10 ⁹ Ω	

Note: See electrical characteristics

-OUT c IN

Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
DC supply voltage	V _{DD} -V _{SS}	-0.5 to 20	V
DC supply voltage	V _{DD} -V _{EE}	-0.5 to 20	V
Control input voltage	V _{CIN}	$V_{SS}{-}0.5$ to $V_{DD}{+}0.5$	V
Switch I/O voltage	V _I /V _O	$V_{\mbox{\scriptsize EE}}-0.5$ to $V_{\mbox{\scriptsize DD}}+0.5$	V
Control input current	ICIN	±10	mA
Potential difference across I/O during ON	VI-VO	-0.5 to 0.5	V
Power dissipation	PD	300 (DIP)/180 (SOIC)	mW
Operating temperature range	T _{opr}	-40 to 85	°C
Storage temperature range	T _{stg}	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit	
DC supply voltage	V _{DD} -V _{SS}		3	_	18	V	
DC supply voltage	V _{DD} -V _{EE}		3	_	18	v	
Control input voltage	V _{IN}		V_{SS}	_	V _{DD}	V	
Input/output voltage	V _{IN} /V _{OUT}	_	V_{EE}		V _{DD}	V	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused Control inputs must be tied to either V_{DD} or V_{SS} .

Static Electrical Characteristics

		Test Condition				-40	0°C		25°C	_	85°C		
Characteristics	Symbol		V _{SS} (V)	V _{EE} (V)	V _{DD} (V)	Min	Max	Min	Тур.	Max	Min	Max	Unit
Control input high voltage			V	Vee	5	3.5	_	3.5	2.75	—	3.5	_	
	VIH		$V_{EE} = V_{SS}$ R _L = 1 k Ω		10	7.0		7.0	5.50	—	7.0	—	V
		$V_{IS} = V_{DD}$	to V _S	S S	15	11.0		11.0	8.25		11.0		
Control input low		thru 1 kΩ	I _{IS} < 2	2 μΑ	5	—	1.5	—	2.25	1.5	—	1.5	
Control input low voltage	VIL		on all chanr		10	—	3.0	—	4.5	3.0	_	3.0	V
				1	15	_	4.0		6.75	4.0		4.0	
On state		$0 \le V_{IS} \le V_{DD}$	0	0	5	—	850	—	240	950	_	1200	
On-state resistance	R _{ON}	$R_L = 10 k\Omega$	0	0	10	—	210	—	110	250	_	300	Ω
			0	0	15	_	140		80	160	_	200	
∆On-state	R _{ON} ∆	_	0	0	5	—		—	10	—			
resistance between any 2			0	0	10	—		—	6	—			Ω
switches			0	0	15	—	—		4	—	_	—	
Input/output	I _{OFF}	V _{IN} = 18 V, V _{OUT} = 0 V V _{IN} = 0 V, V _{OUT} = 18 V			18	—	±100	—	±0.01	±100		±1000	nA
leakage current					18	_	±100	_	±0.01	±100		±1000	
	I _{DD}		(Note)		5	—	5.0	—	0.005	5.0	—	150	
Quiescent supply current		$V_{IN}=V_{SS},\ V_{DD}$			10	—	10	—	0.010	10	—	300	μA
					15	_	20	_	0.015	20		600	
Input current	I _{IN}	$V_{IH} = 18 V$ $V_{IL} = 0 V$			18	—	0.1	—	10 ⁻⁵	0.1	—	1.0	μA
input current					18	_	-0.1	_	-10 ⁻⁵	-0.1		-1.0	μА
Input capacitance	C _{IN}				_	_		_	5	7.5			pF
Switch input capacitance	C _{IN}	—			_	—	_	—	10	_	—	—	pF
		TC4051B TC4052B		10	_	_	_	58	_		_		
Output capacitance	COUT			10	—	—	—	30	—	—	—	pF	
		TC4053B			10	—		—	17	—	_		
		TC4051B			10	_		_	0.2		_		
Feedthrough capacitance	C _{IN} - C _{-OUT}	TC4052B		10	_		_	0.2	—	_		pF	
		TC4053B			10	—		_	0.2	_	_		

Note: All valid input combinations.

Dynamic Electrical Characteristics (Ta = 25°C, C_L = 50 pF)

		Test Condition								
Characteristics	Symbol		V _{SS} (V)	V _{EE} (V)	V _{DD} (V)	Min	Тур.	Max	Unit	
				0	0	5	_	15	45	
Phase difference between input to output	ф І-О			0	0	10	—	8	20	ns
			0	0	15	_	6	15		
	t			0	0	5	—	170	550	
Propagation delay time	t _{pZL}			0	0	10	—	90	240	
(A, B, C, -OUT)	t _{pZH}	$R_L = 1 \ k\Omega$		0	0	15	—	70	160	ns
(A, B, C, -001)	t _{pLZ}			0	-5	5	—	100	240	
	t _{pHZ}			0	-7.5	7.5	—	80	160	
				0	0	5	—	120	380	
Propagation dolay time	+			0	0	10	—	60	200	ns
Propagation delay time	t _{pZL} t _{pZH}	$R_L = 1 \ k\Omega$		0	0	15	—	50	160	
(INH-OUT)				0	-5	5	—	80	200	
				0	-7.5	7.5	—	60	160	
	t _{pLZ} t _{pHZ}			0	0	5	_	170	450	
Propagation delay time				0	0	10	—	90	210	
		$R_L = 1 \ k\Omega$		0	0	15	—	70	160	ns
(INH-OUT)				0	-5	5	—	100	210	
				0	-7.5	7.5	—	80	160	
-3dB cutoff frequency				-5	-5	5		20		
TC4051B	f _{max} (I-O)	$R_L = 1 k\Omega$	(Note 1)		_5 _5	5		30		MHz
TC4052B	Imax (I-O)			-5 -5	-5 -5	5	_	40		
TC4053B				-5	-5	5		40		
		R _L = 10 kΩ		-2.5	-2.5	2.5	—	0.15	—	
Total harmonic distortion	—	f = 1 kHz	(Nata 0)	-5	-5	5	—	0.03	—	%
			(Note 2)	-7.5	-7.5	7.5	_	0.02	—	
-50dB feedthrough		$R_L = 1 k\Omega$	(Note 3)	-5	-5	5	_	500		kHz
(switch off)	_	$\Gamma L = 1 K S 2$	(Note 3)	-5	-5	5	_	500		NI IZ
Crosstalk	_	$R_L = 1 \ k\Omega$	(Note 4)	-5	-5	5	_	1.5	_	MHz
Crosstalk	_	$R_{IN} = 1 \ k\Omega$		0	0	5	_	200	_	
Crosstalk		$R_{OUT} = 10 \ k\Omega$		0	0	10	—	400	—	mV
(control-OUT)		$C_L = 15 \text{ pF}$		0	0	15	—	600	—	

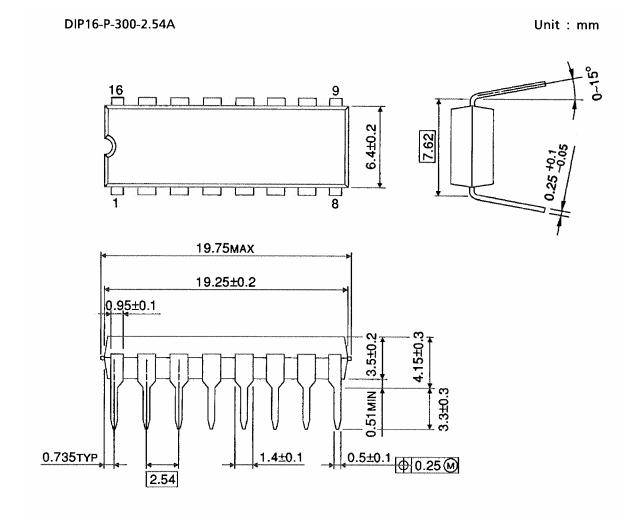
Note 1: Sine wave of $\pm 2.5 V_{p-p}$ shall be used for V_{is} and the frequency of 20 log 10 $\frac{V_{OS}}{V_{is}} = -3dB$ shall be f_{max}.

Note 2: V_{is} shall be sine wave of
$$\pm \left(\frac{V_{DD} - V_{EE}}{4}\right)$$
 p-p.

Note 3: Sine wave of $\pm 2.5 \text{ V}_{p-p}$ shall be used for V_{is} and the frequency of 20 log 10 $\frac{\text{V}_{OS}}{\text{V}_{is}} = -50 \text{dB}$ shall be feed-through.

Note 4: Sine wave of $\pm 2.5 V_{p-p}$ shall be used for V_{is} and the frequency of 20 log 10 $\frac{V_{OS}}{V_{is}} = -50 dB$ shall be crosstalk.

Package Dimensions



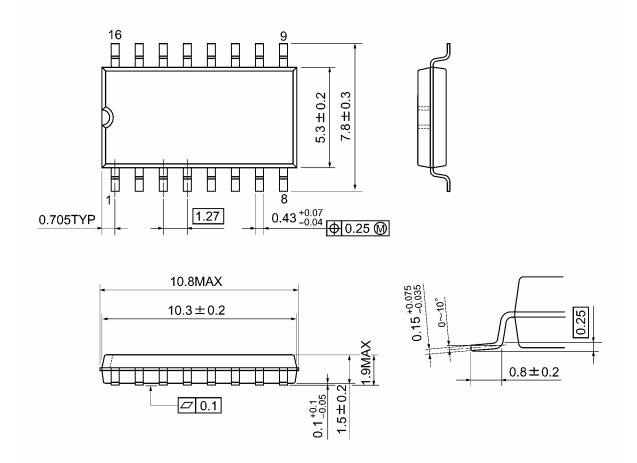
Weight: 1.00 g (typ.)



Package Dimensions

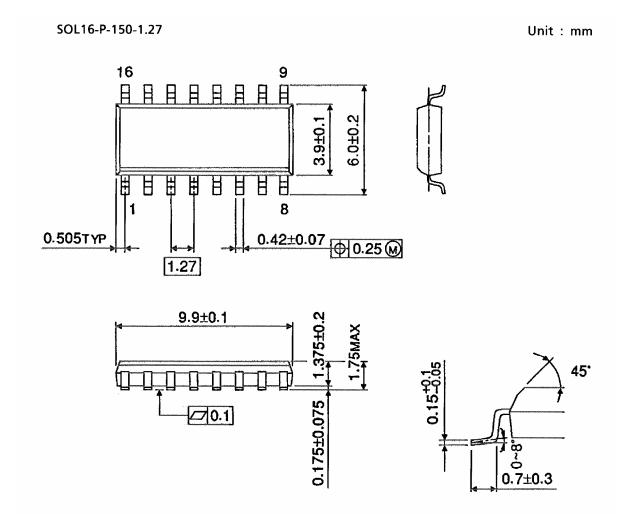
SOP16-P-300-1.27A

Unit: mm



Weight: 0.18 g (typ.)

Package Dimensions (Note)



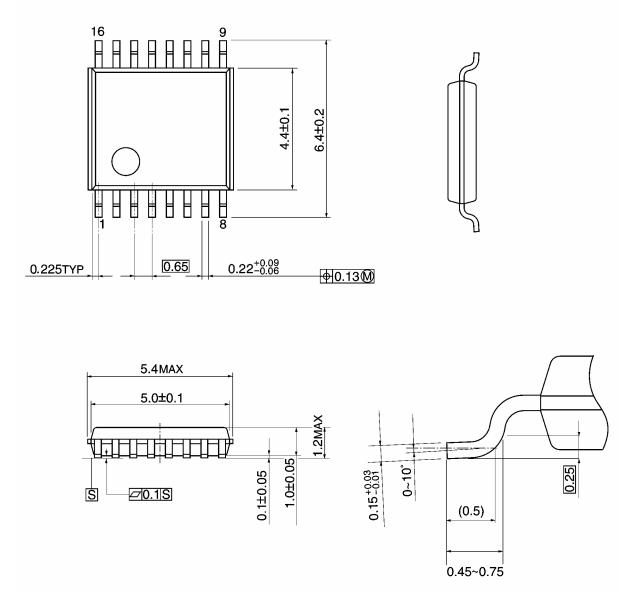
Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

Package Dimensions

TSSOP16-P-0044-0.65A

Unit: mm



Weight: 0.06 g (typ.)

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20070701-EN

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